Diode Semiconductor Device - Page 1 of 1



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	nclosure Material:
G	Blass
C	Overall Length:
0	.350 inches
Т	erminal Length:
1	.000 inches
С	Overall Diameter:
0	.140 inches
	unction For Which Designed:
Z	ener diode
N	Iounting Method:
Т	erminal
F	eatures Provided:
Η	lermetically sealed case
S	emiconductor Material:
S	ilicon
۷	oltage Rating In Volts Per Characteristic:
3	.3 regulator voltage
۷	oltage Tolerance In Percent:
-2	20.0/+20.0
С	Current Rating Per Characteristic:
3	80.00 milliamperes all primaries horsepower metric
Ρ	ower Rating Per Characteristic:
5	.0 watts small-signal input power, common-collector absolute
N	Iaximum Operating Tempurature Per Measurement Point:
2	00.0 degrees celsius ambient air
Т	erminal Type And Quantity:
2	uninsulated wire lead
S	pecification Data:
8	0131-release5750 professional/industrial association specification
S	shelf Life:
N	I/a
U	Init Of Measure:
D	Demilitarization:
N	lo
F	iig:
	.110a0